



JAN2N3637UB Information

Heisener.com

Part Number JAN2N3637UB

Manufacturer Microsemi Corporation

Category Discrete Semiconductor Products

Transistors - Bipolar (BJT) - Single

Description TRANS PNP 175V 1A

3-SMD, No Lead **Package**

For the pricing/inventory/lead time, please contact

Website: https://www.heisener.com For Reference Only

E-mail: salesdept@heisener.com



Request a Quote

Certified Quality

Heisener's commitment to quality has shaped our processes for sourcing, testing, shipping, and every step in between. This foundation underlies each component we sell.









JAN2N3637UB Specifications

Manufacturer Part Number	JAN2N3637UB
Manufacturer	Microsemi Corporation
Category	Discrete Semiconductor Products
	Transistors - Bipolar (BJT) - Single
Package	3-SMD, No Lead
Series	Military, MIL-PRF-19500/357
Transistor Type	PNP
Current - Collector (Ic) (Max)	1A
Voltage - Collector Emitter Breakdown (Max)	175V
Vce Saturation (Max) @ Ib, Ic	600mV @ 5mA, 50mA
Current - Collector Cutoff (Max)	10μΑ
DC Current Gain (hFE) (Min) @ Ic, Vce	100 @ 50mA, 10V
Power - Max	1.5W
Frequency - Transition	-
Operating Temperature	-65°C ~ 200°C (TJ)
Mounting Type	Surface Mount
Package / Case	3-SMD, No Lead
Supplier Device Package	3-SMD
	Report errors?

JAN2N3637UB Guarantees



Quality Guarantees

We provide 90 days warranty. *

If the items you received were not in perfect quality, we would be responsible for your refund or replacement, but the items must be returned in their original condition.



Service Guarantees

We guarantee 100% customer satisfaction.

Our experienced sales team and tech support team back our services to satisfy all our customers.

JAN2N3637UB Payment Methods



















JAN2N3637UB Shipping Methods













If you have any question about JAN2N3637UB, please do not hesitate to contact us!

Website: https://www.heisener.com E-mail: salesdept@heisener.com